

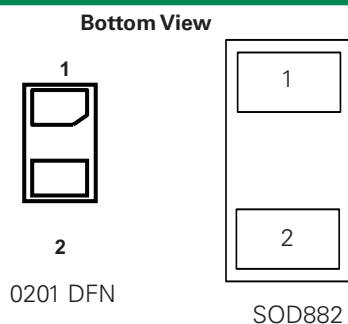
SP3522 0.15pF 22kV avalanche diodes



Description

The SP3522 integrates ultra low capacitance cathode-to-cathode silicon avalanche diodes to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust component can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard ($\pm 8\text{kV}$ contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as V-By-One®, HDMI, USB3.0, USB2.0, and IEEE 1394.

Pinout



Features

- ESD, IEC 61000-4-2, $\pm 22\text{kV}$ contact, $\pm 22\text{kV}$ air
- EFT, IEC 61000-4-4, 40A ($t_p=5/50\text{ns}$)
- Lightning, IEC 61000-4-5, 2nd edition, 2.5A ($t_p=8/20\mu\text{s}$)
- Low capacitance of 0.15pF (TYP) at 3GHz
- Low profile 0201 DFN packages and SOD882 packages
- Facilitates excellent signal integrity
- ELV Compliant
- AEC-Q101 qualified
- Halogen free, Lead free and RoHS compliant
- Moisture Sensitivity Level (MSL-1)

Functional Block Diagram



Applications

- Ultra-high speed data lines
- USB 3.1, 3.0, 2.0
- HDMI 2.0, 1.4a, 1.3
- DisplayPort™
- V-by-One®
- LVDS interfaces
- Consumer, mobile and portable electronics
- Tablet PC and external storage with high speed interfaces
- Applications requiring high ESD performance in small packages

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p=8/20\mu s$)	2.5	A
T_{OP}	Operating Temperature	-45 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics - ($T_{OP}=25^{\circ}C$)

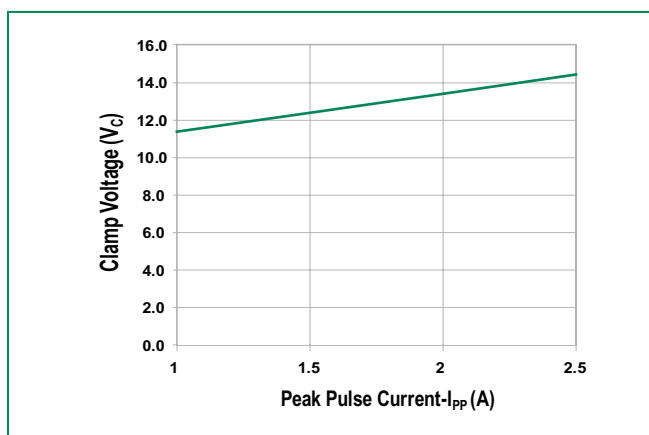
Parameter	Test Conditions	Min	Typ	Max	Units
Input Capacitance	@ $V_R = 0V$, $f = 3GHz$		0.15		pF
Breakdown Voltage	V_{BR} @ $I_T=1mA$		9.2		V
Reverse Working Voltage	$I_R \leq 1\mu A$			7.0	V
Reverse Leakage Current	I_L @ $V_{RWM}=5.0V$		0.02	1	μA
Dynamic Resistance ²	TLP, $t_p=100ns$, I/O to GND		0.96		Ω
Clamping Voltage ¹	V_{CL} @ $I_{PP}=2.5A$		14.5		V
ESD Withstand Voltage ¹	IEC 61000-4-2 (Contact)	± 22			kV
	IEC 61000-4-2 (Air)	± 22			

Note:

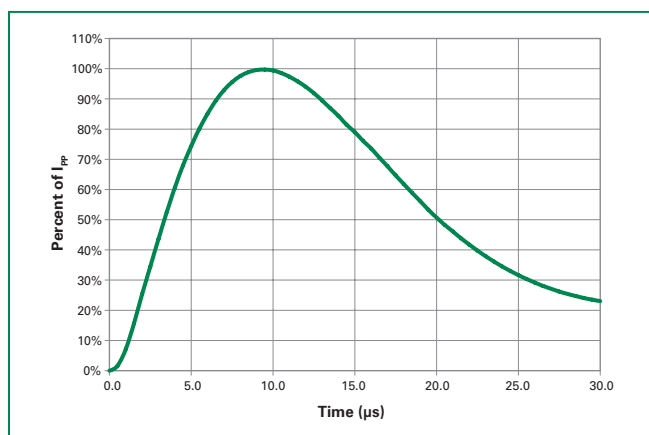
1. Parameter is guaranteed by design and/or component characterization.

2. Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window $t_1=70ns$ to $t_2=90ns$

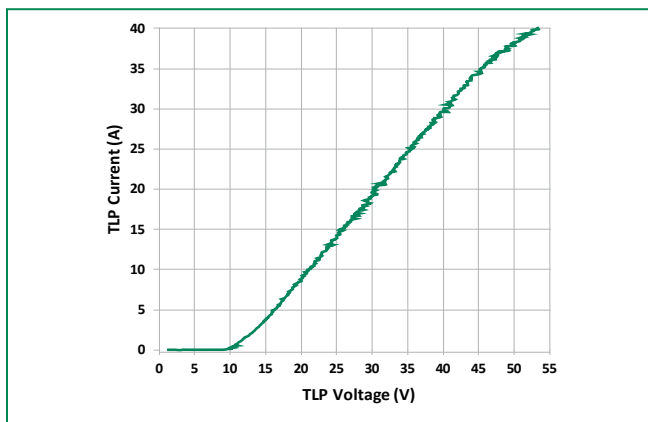
Clamping Voltage vs I_{PP}



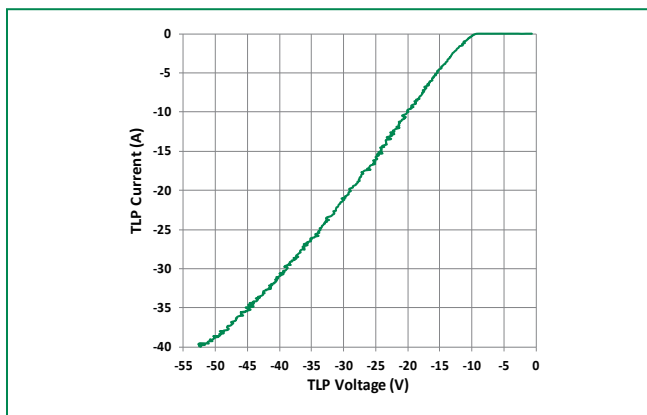
8/20 μs Pulse Waveform



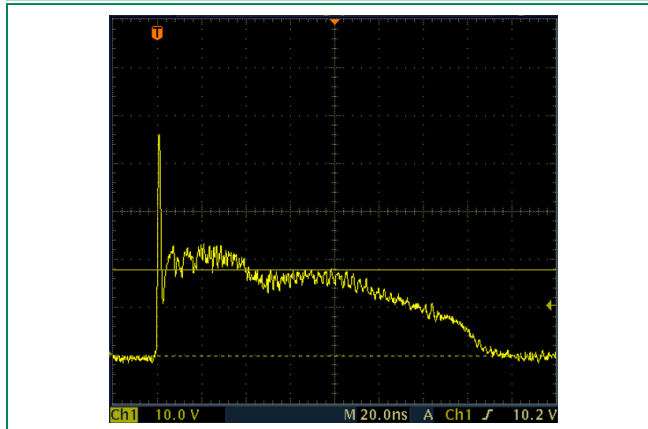
Positive Transmission Line Pulsing (TLP) Plot



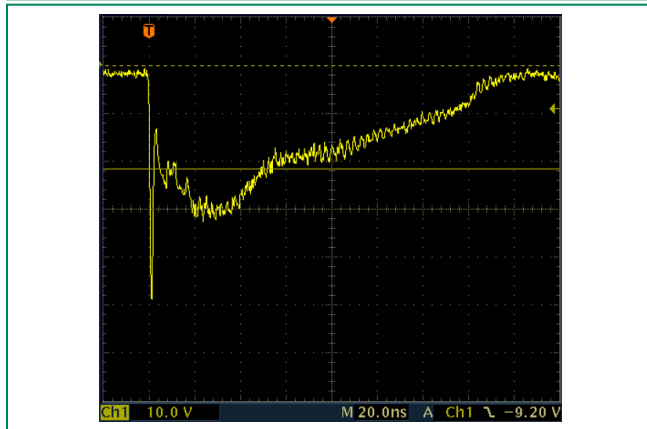
Negative Transmission Line Pulsing (TLP) Plot



IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage

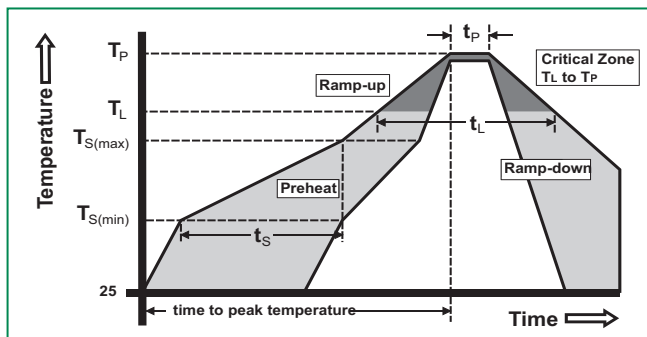


IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage

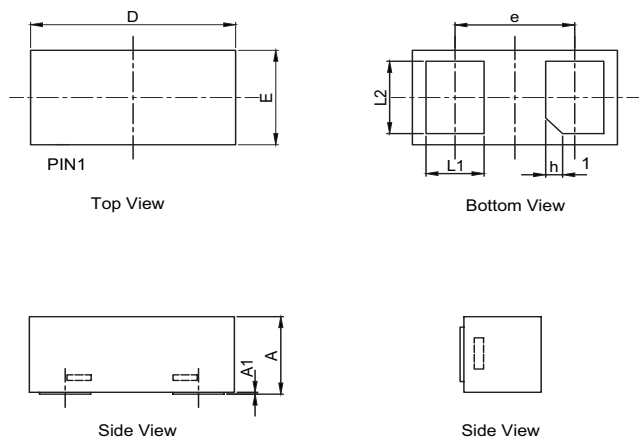


Soldering Parameters

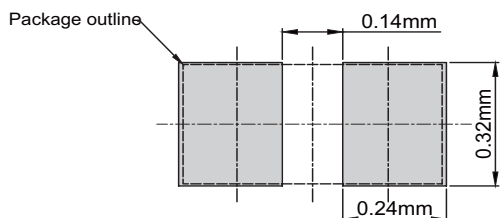
Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



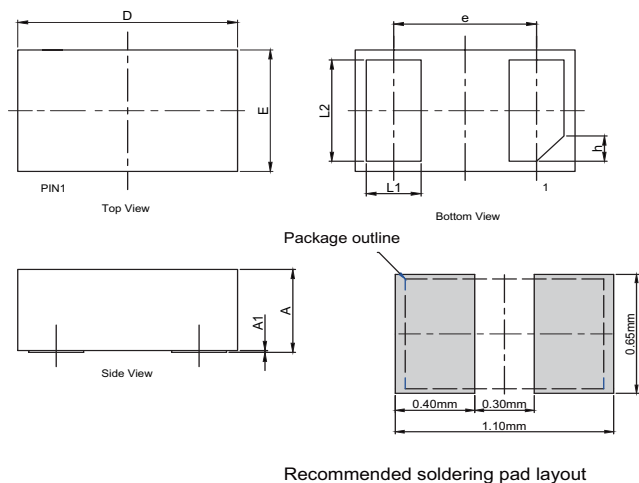
Package Dimensions — 0201 DFN



Symbol	Millimeters			Inches		
	Min	Max	Max	Min	Min	Max
A	0.23	0.28	0.33	0.009	0.011	0.013
A1	0.00	0.02	0.05	0.000	0.001	0.002
L1	0.12	0.18	0.24	0.005	0.007	0.009
L2	0.18	0.24	0.30	0.007	0.009	0.012
D	0.55	0.60	0.65	0.022	0.024	0.026
E	0.25	0.30	0.35	0.010	0.012	0.014
e	0.35 (BSC)			0.014 (BSC)		
h	0.05 (x 45°)			0.002 (x 45°)		

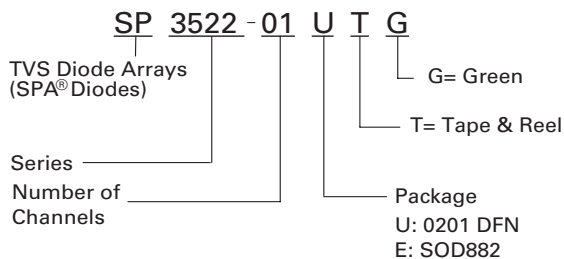


Package Dimensions — SOD882

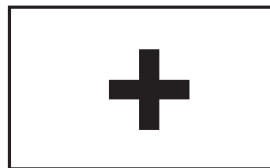


Symbol	Millimeters			Inches		
	Min	Max	Max	Min	Min	Max
A	0.40	0.45	0.50	0.016	0.018	0.020
A1	0.00	0.02	0.05	0.000	0.001	0.002
L1	0.20	0.25	0.30	0.008	0.010	0.012
L2	0.45	0.50	0.55	0.018	0.020	0.022
D	0.90	1.00	1.10	0.035	0.039	0.043
E	0.50	0.60	0.70	0.020	0.024	0.028
e	0.65 (BSC)			0.026 (BSC)		
h	0.125 (x 45°)			0.005 (x 45°)		

Part Numbering System



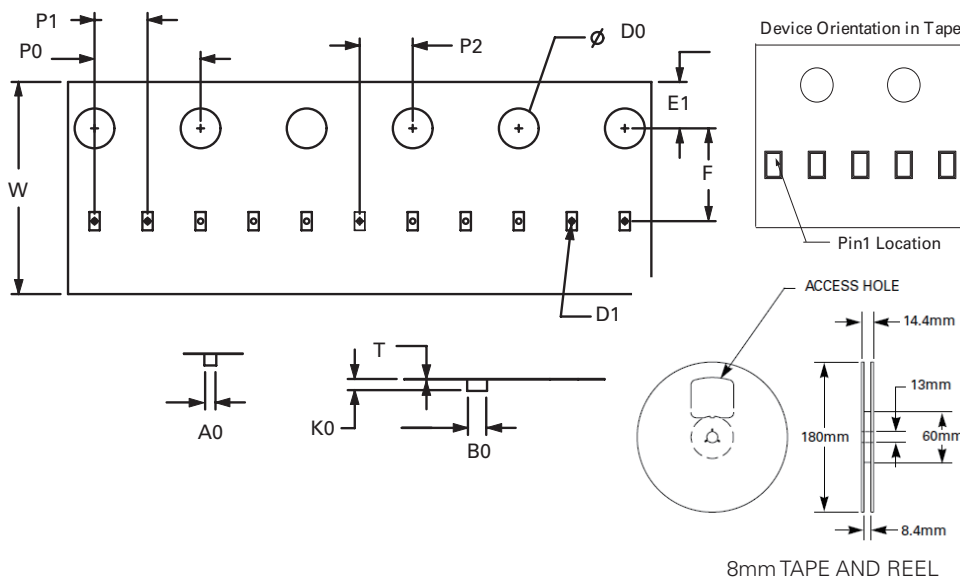
Part Marking System



Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SP3522-01UTG	0201 DFN	+	15000
SP3522-01ETG	SOD882		10000

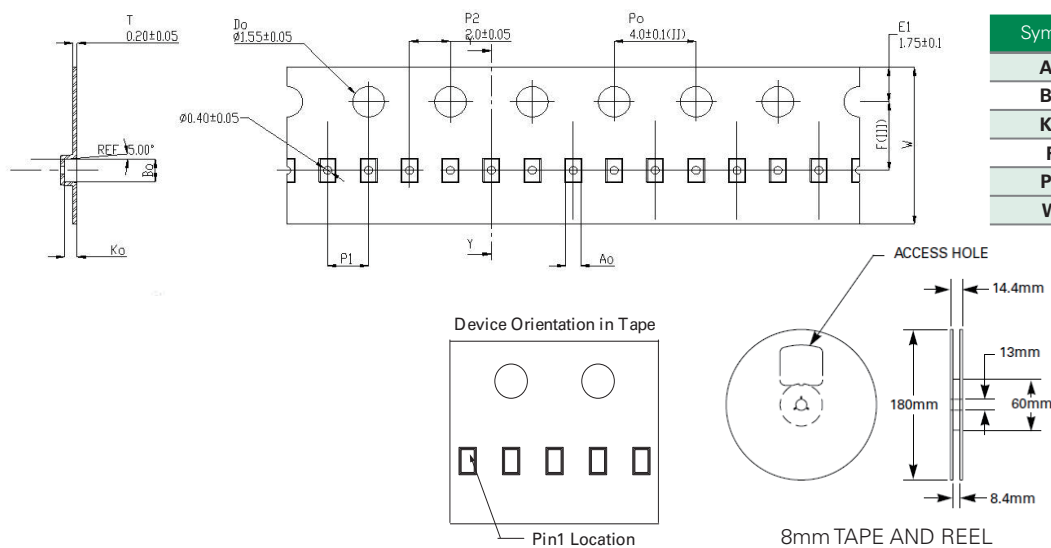
Embossed Carrier Tape & Reel Specification — 0201 DFN



Symbol	Millimeters
A0	0.33 min/0.41 max
B0	0.63 min/0.71 max
D0	ø 1.50 +0.10/-0
D1	ø 0.20 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.30 min/0.39 max
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00+0.30/-0.10
T	0.13 min/0.25 max

8mm TAPE AND REEL

Embossed Carrier Tape & Reel Specification — SOD882



Symbol	Millimeters
A0	0.70+/-0.045
B0	1.10+/-0.045
K0	0.65+/-0.045
F	3.50+/-0.05
P1	2.00+/-0.10
W	8.00 + 0.30 -0.10

8mm TAPE AND REEL

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